



SANYO Semiconductors

DATA SHEET

TND516SS ExPD(Excellent Power Device) Single-phase High Side Drive Application

Features

- Single-phase high side driver.
- Monolithic structure.
- Allows simplified configuration of driver circuit.
- Withstand voltage of 600V is assured.
- Fully compatible input to LSTTL/CMOS.
- High-speed switching.
- Output current : 170mA Source, 340mA Sink.

Specifications

Absolute Maximum Ratings at Ta=25°C (All voltage parameters are absolute voltage referenced to GND)

Parameter	Symbol	Conditions	Ratings	Unit
High Side Floating Supply Voltage	V _H		-0.3 to 625	V
High Side Floating Supply Offset Voltage	V _S		V _H -25 to V _H +0.3	V
High Side Output Voltage	V _{HOUT}		V _S -0.3 to V _H +0.3	V
Logic Supply Voltage	V _{DD}		-0.3 to 25	V
Logic Input Voltage	V _{HIN}		-0.3 to V _{DD} +0.3	V
Allowable Power Dissipation	P _D		0.3	W
Junction Temperature	T _J		-55 to +150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Recommended Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
High Side Floating Supply Voltage	V _H		V _S +10 to V _S +20	V
High Side Floating Supply Offset Voltage	V _S		0 to 600	V
High Side Output Voltage	V _{HOUT}		V _S to V _H	V
Logic Supply Voltage	V _{DD}		10 to 20	V
Logic Input Voltage	V _{HIN}		0 to V _{DD}	V
Ambient Temperature	T _{opr}		-40 to +125	°C

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AC Characteristics at Ta=25°C (VDD=VHS=15V, CL=1000pF)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Turn-ON Delay Time	t _{on}	V _S =0V		155		ns
Turn-OFF Delay Time	t _{off}	V _S =600V		135		ns
Turn-ON Rise Time	t _r			110		ns
Turn-OFF Fall Time	t _f			40		ns

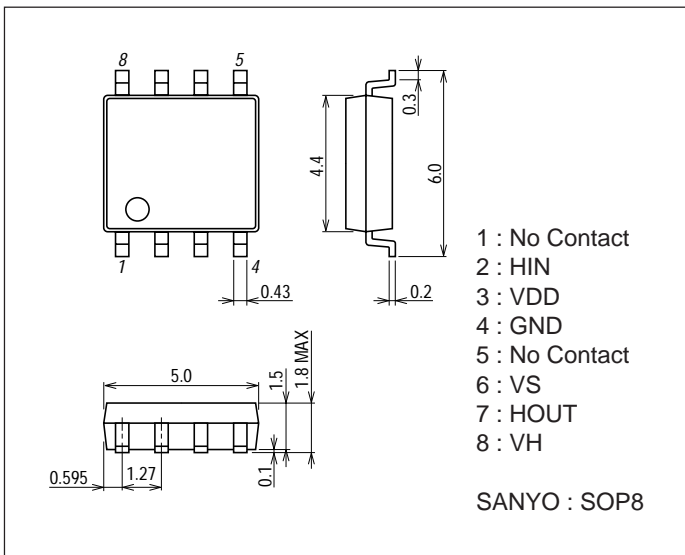
DC Characteristics at Ta=25°C (VDD=VHS=15V)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Logic "1" Input Voltage	V _{IH}	V _{DD} =10 to 20V	3.0			V
Logic "0" Input Voltage	V _{IL}	V _{DD} =10 to 20V			0.8	V
High-level Output Voltage, V _{BIAS} -V _O	V _{OH}	V _{HIN} =V _{IH} , I _O =0A			0.1	V
Low-level Output Voltage, V _O	V _{OL}	V _{HIN} =V _{IL} , I _O =0A			0.1	V
Offset Supply Leakage Current	I _{LK}	V _H =V _S =600V			10	μA
Quiescent V _H Supply Current	I _{QH}	V _{HIN} =0V or V _{DD}		50	100	μA
Quiescent V _{DD} Supply Current	I _{QDD}	V _{HIN} =0V or V _{DD}		140	230	μA
Logic "1" Input Bias Current	I _{IN+}	V _{HIN} =V _{DD}		20	55	μA
Logic "0" Input Bias Current	I _{IN-}	V _{HIN} =0V			1	μA
V _H Supply Undervoltage Positive Going Threshold	V _{HUV+}		7.6	8.9	9.9	V
V _H Supply Undervoltage Negative Going Threshold	V _{HUV-}		6.7	8.1	9.5	V
V _{DD} Supply Undervoltage Positive Going Threshold	V _{DDUV+}		7.6	8.9	9.9	V
V _{DD} Supply Undervoltage Negative Going Threshold	V _{DDUV-}		6.7	8.1	9.5	V
Output High Short Circuit Pulsed Current	I _{O+}	V _{HOUT} =0V, V _{HIN} =15V, PW≤10μs	170	200		mA
Output Low Short Circuit Pulsed Current	I _{O-}	V _{HOUT} =15V, V _{HIN} =0V, PW≤10μs	340	400		mA

Package Dimensions

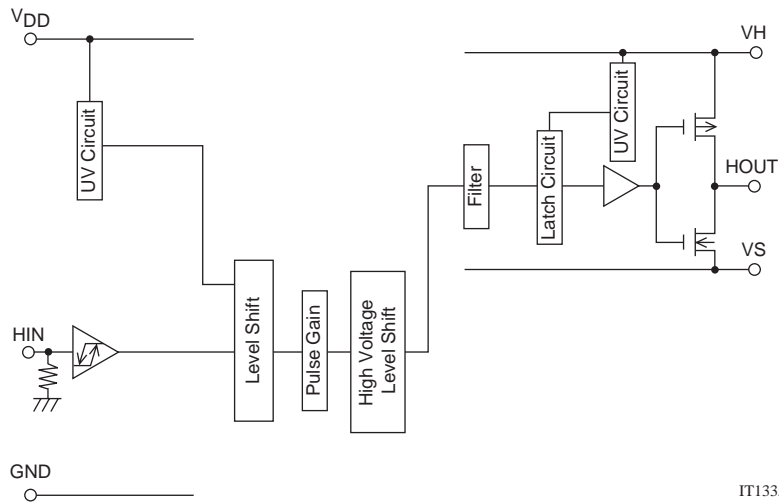
unit : mm (typ)

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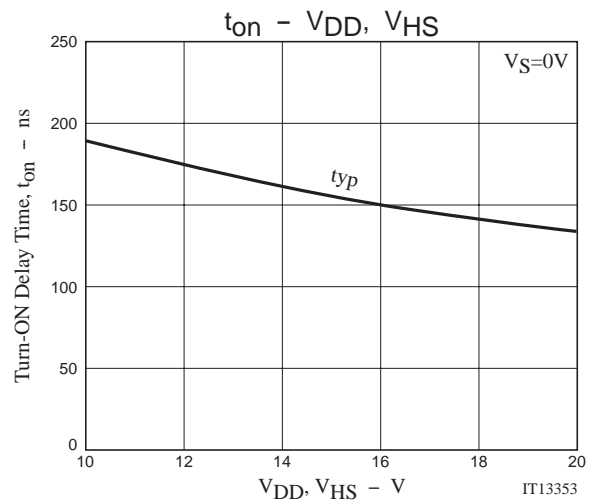
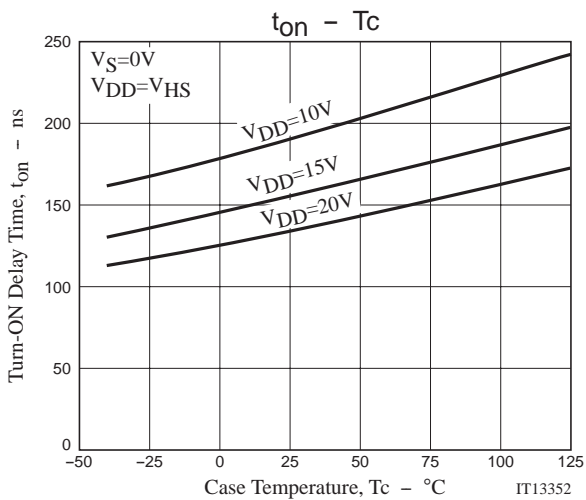
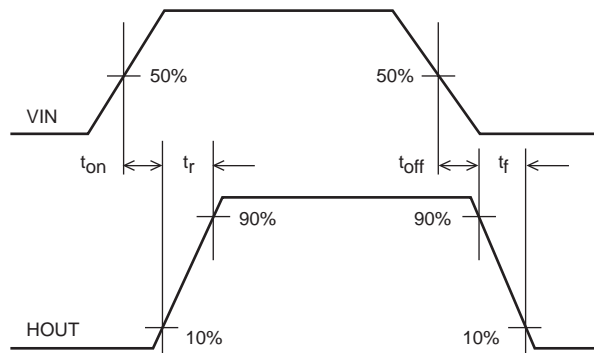
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Block Diagram

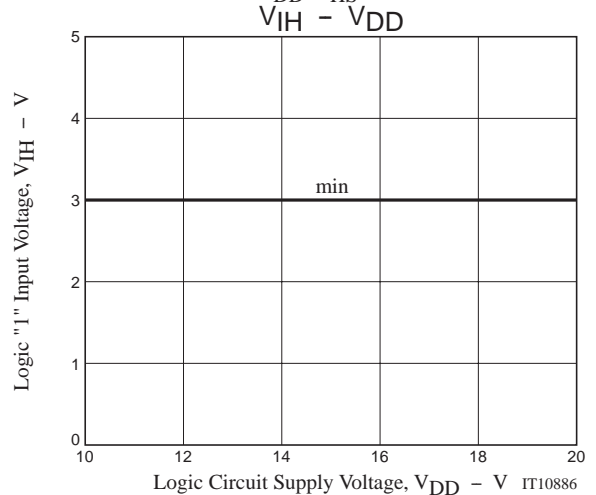
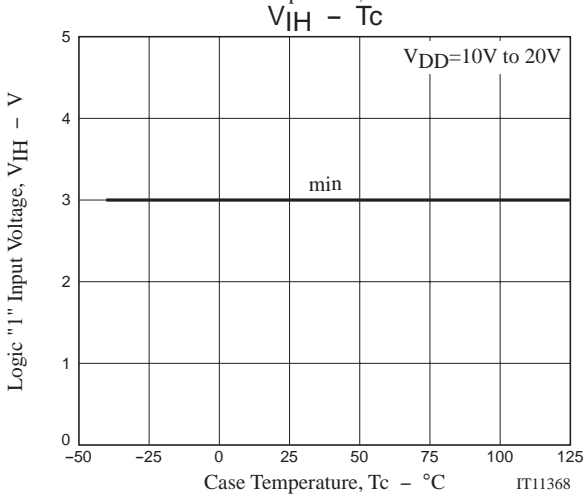
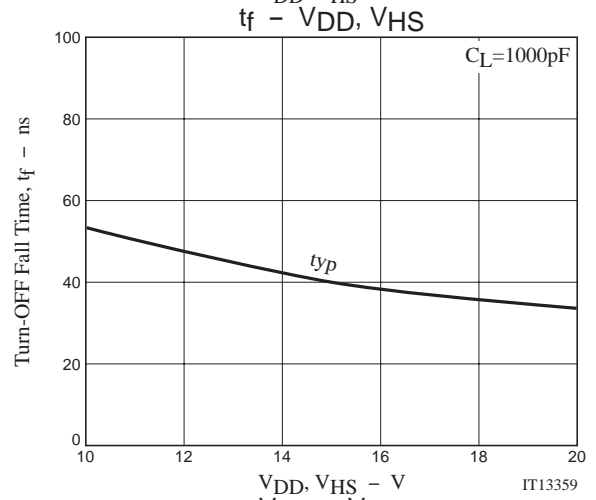
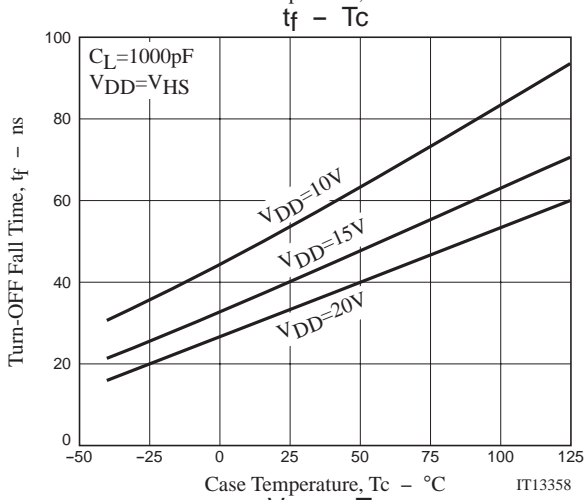
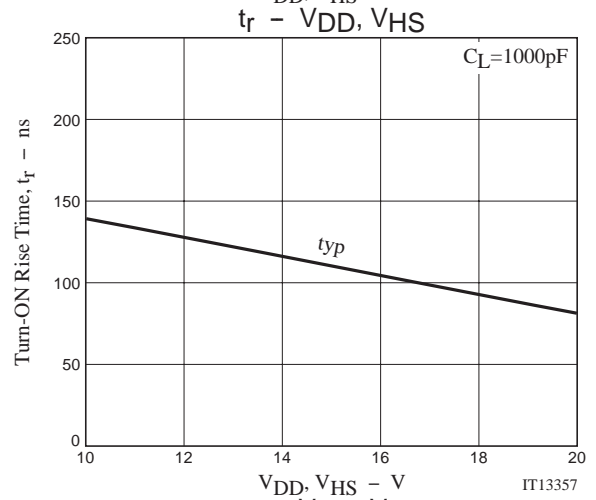
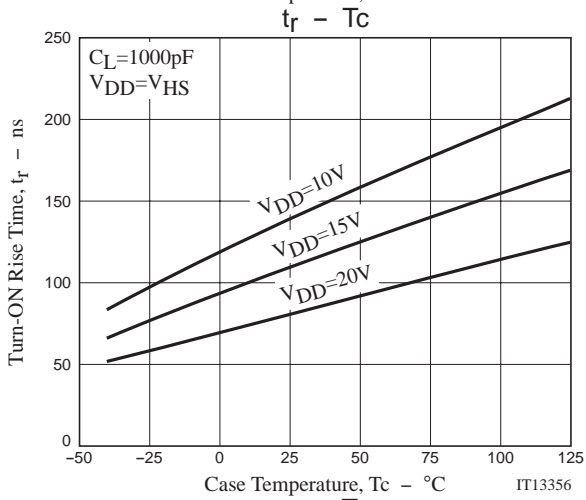
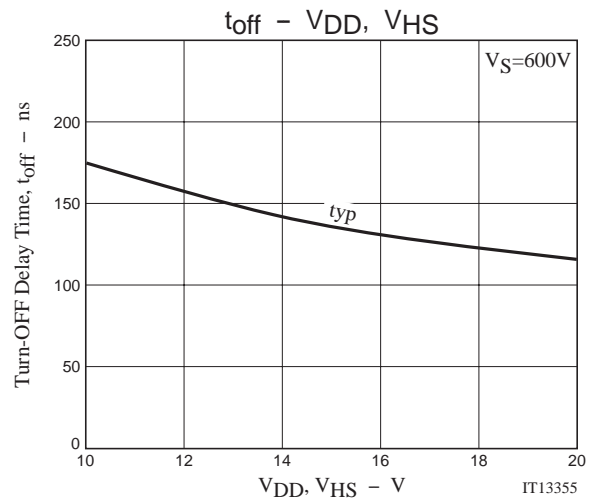
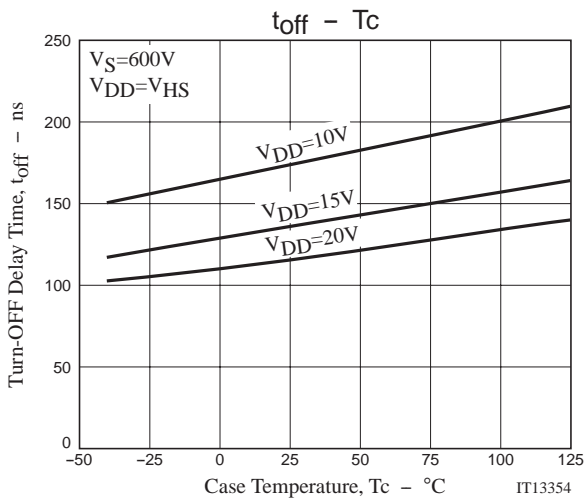


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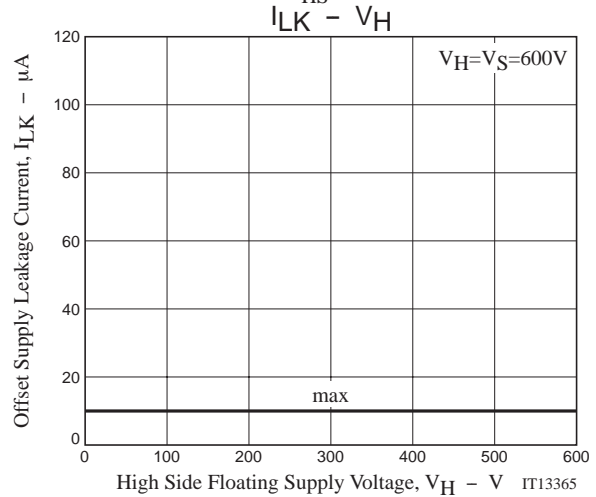
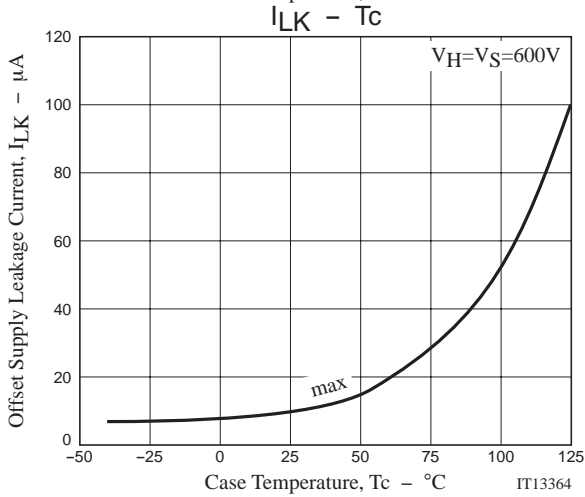
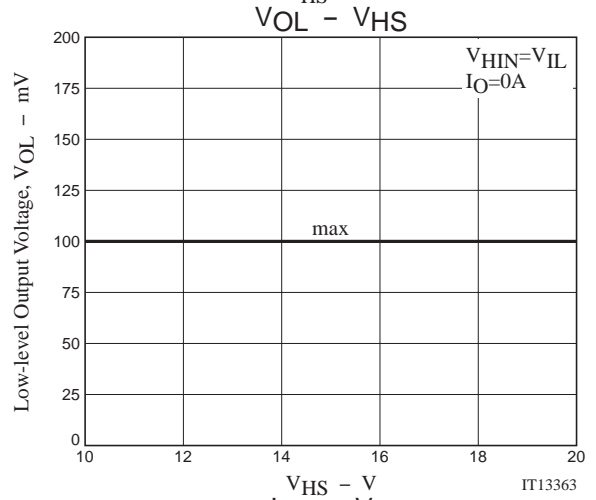
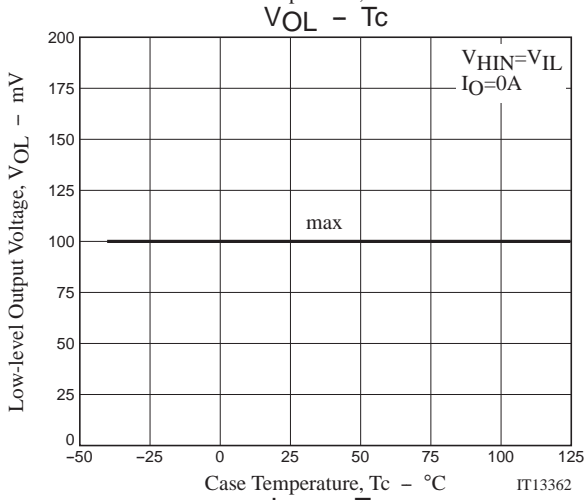
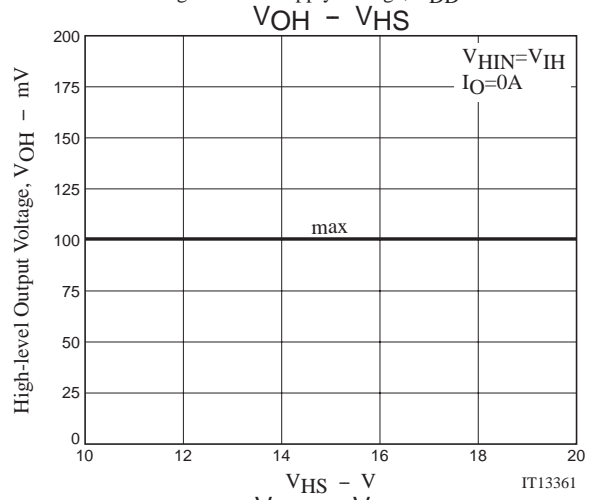
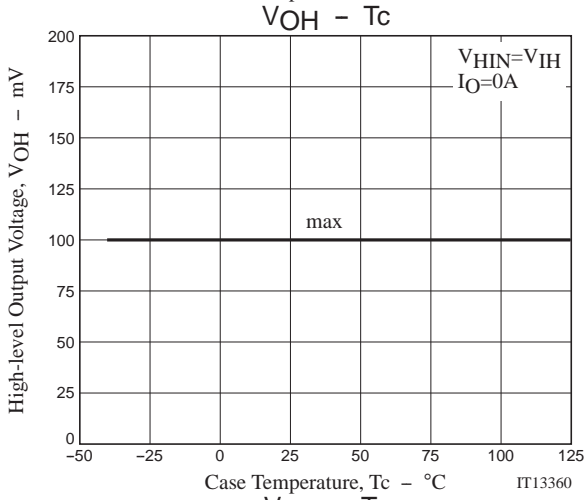
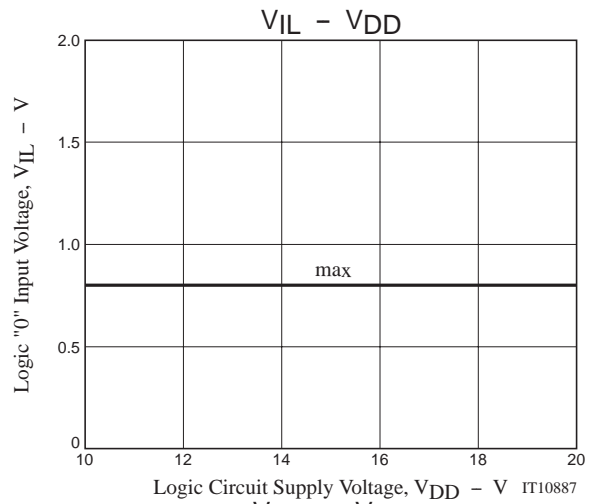
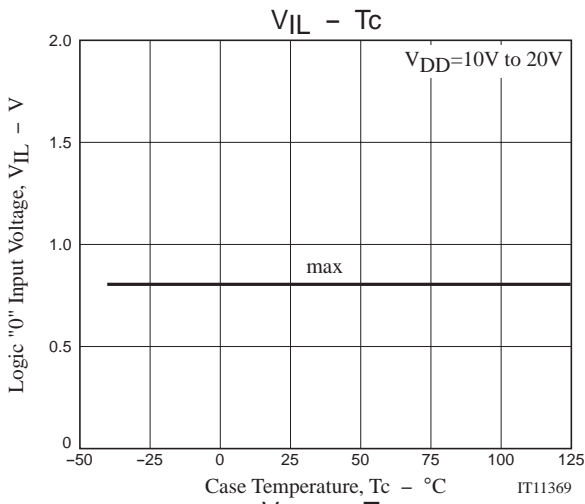
Switching Time Waveform Definition



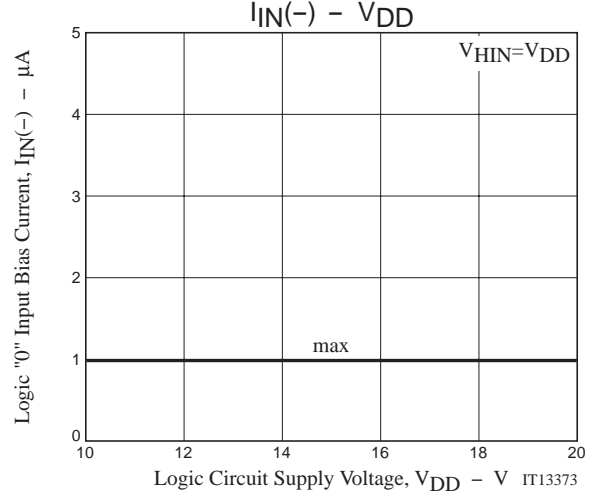
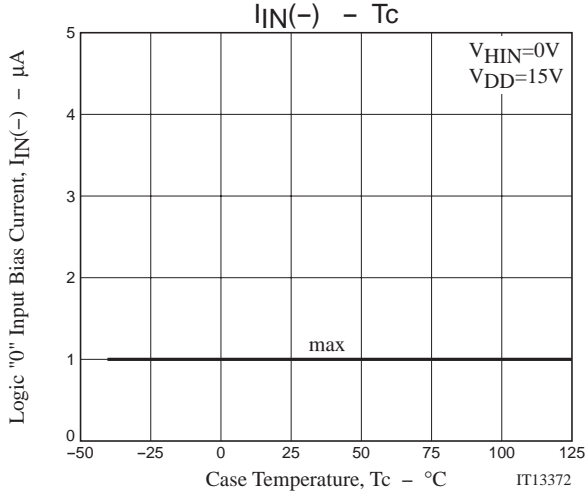
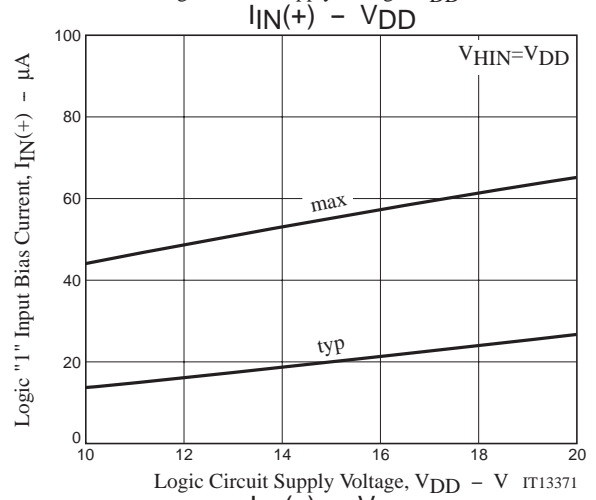
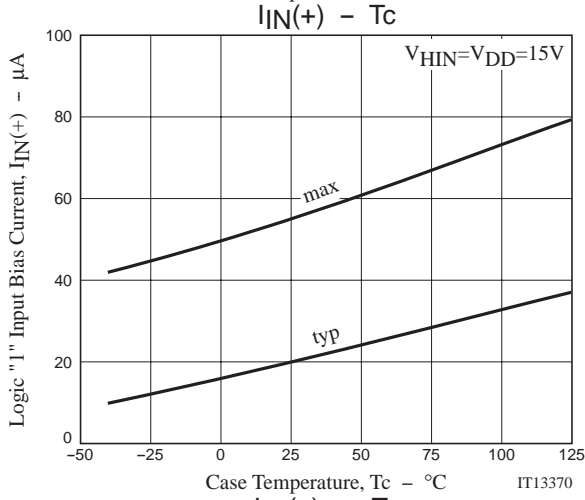
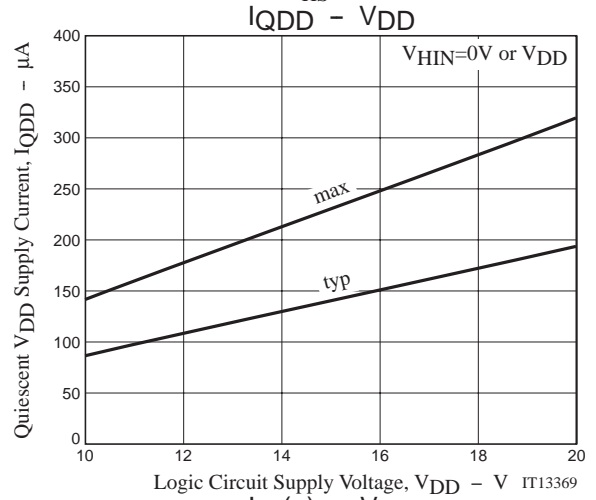
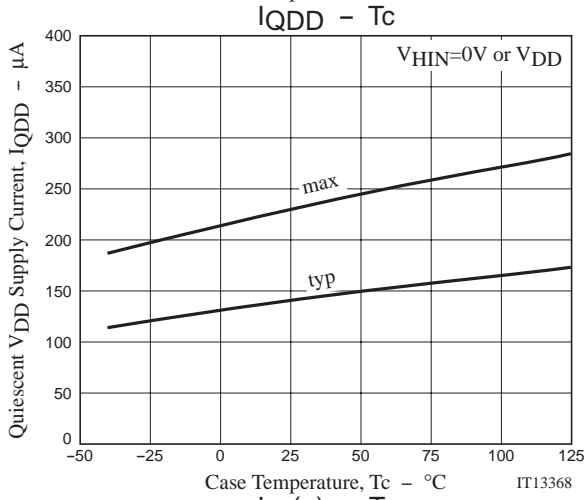
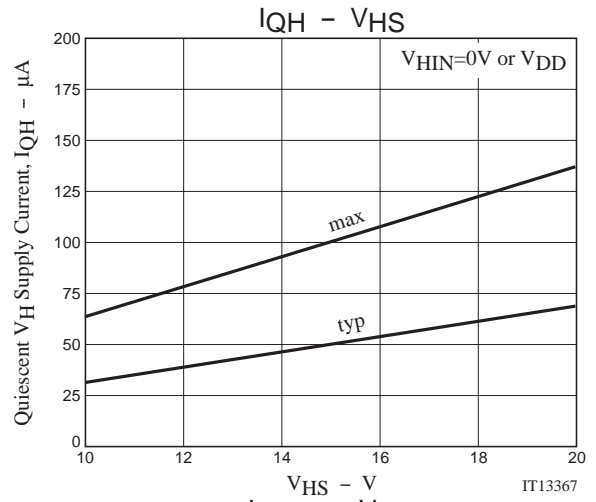
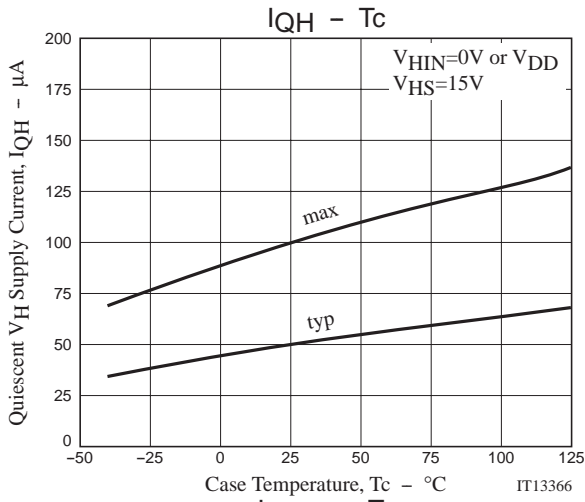
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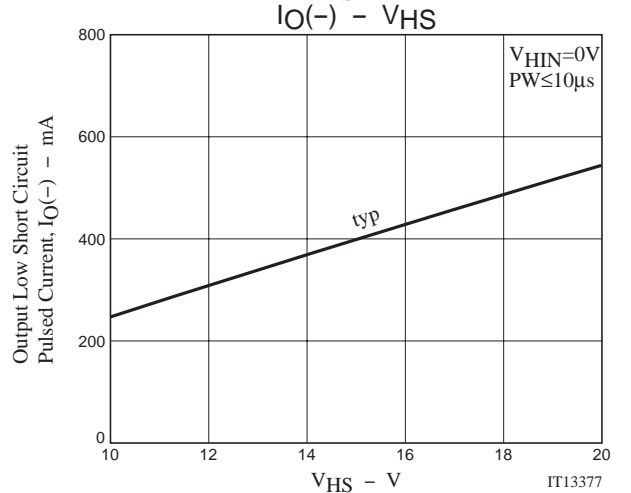
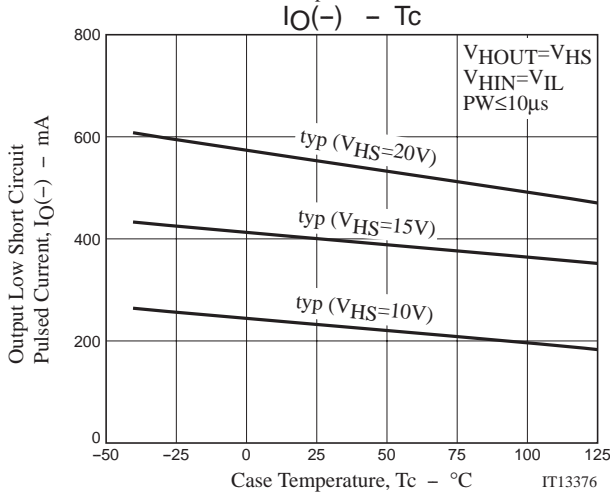
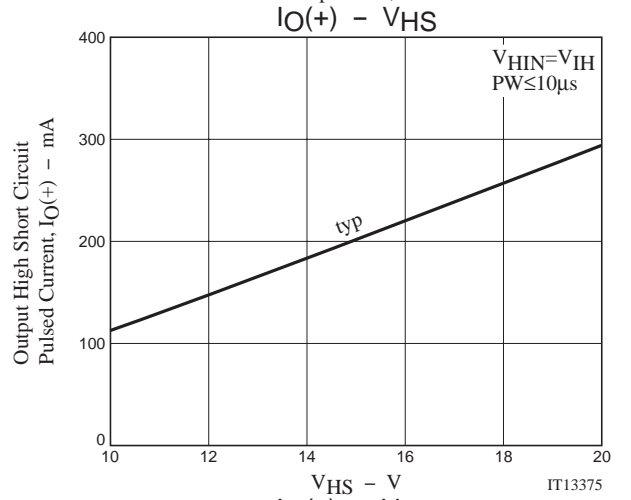
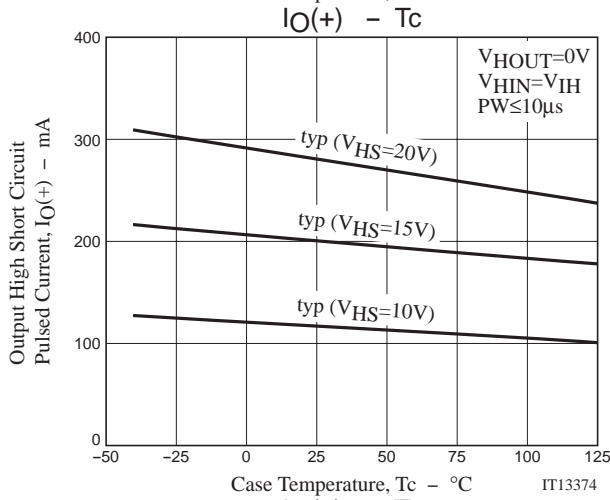
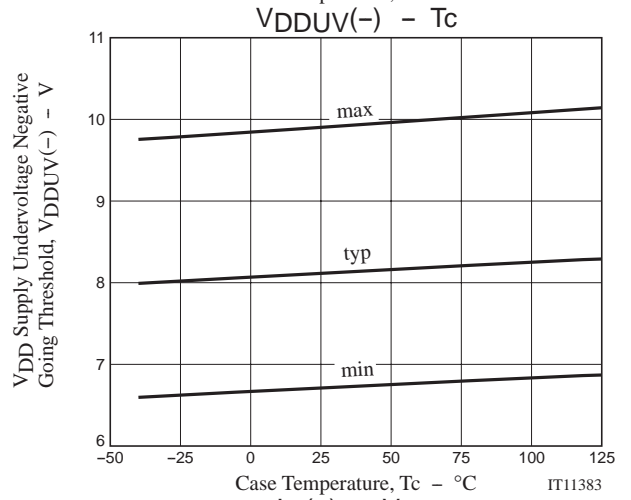
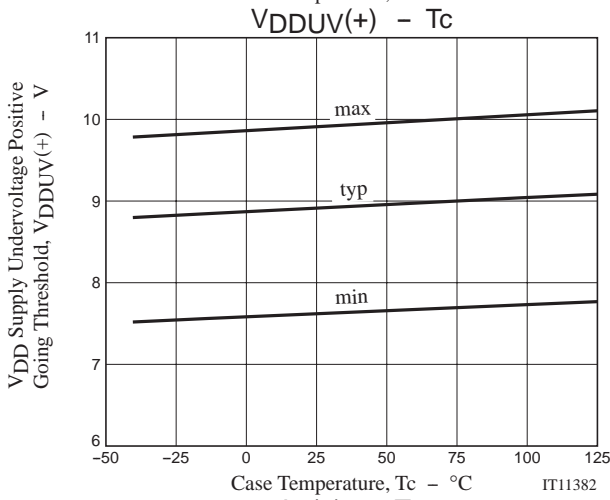
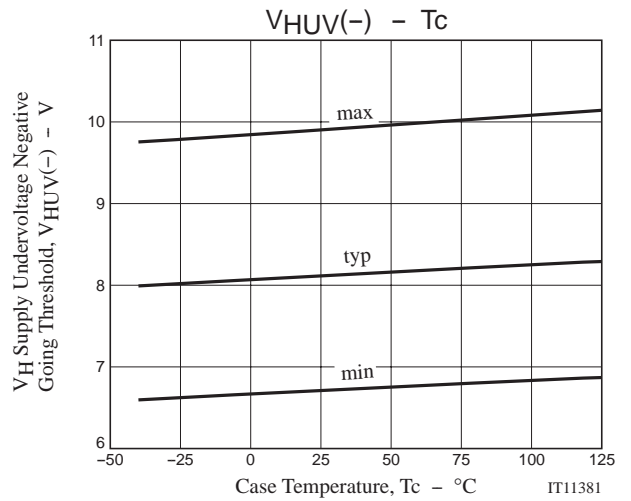
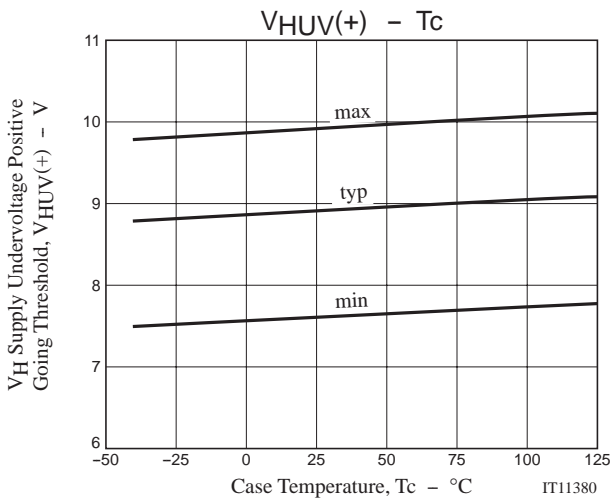
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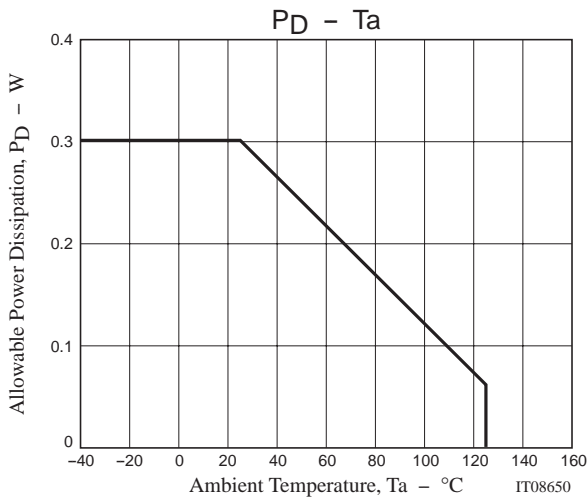
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